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FQD6N50C N-Channel QFET[®] MOSFET 500 V, 4.5 A, 1.2 Ω

Features

- + 4.5 A, 500 V, $R_{DS(on)}$ = 1.2 Ω (Max.) $@V_{GS}$ = 10 V, I_D = 2.25 A
- Low Gate Charge (Typ. 19 nC)
- Low Crss (Typ.15 pF)
- 100% avalanche tested

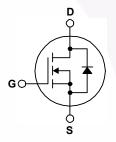
November 2013



Description

This N-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, active power factor correction (PFC), and electronic lamp ballasts.





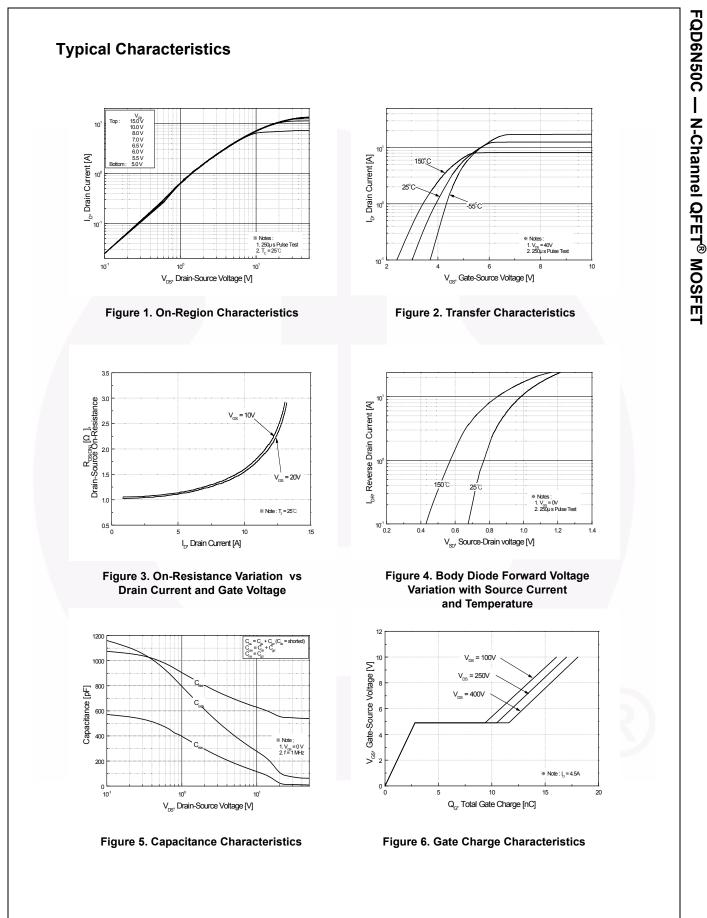
Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

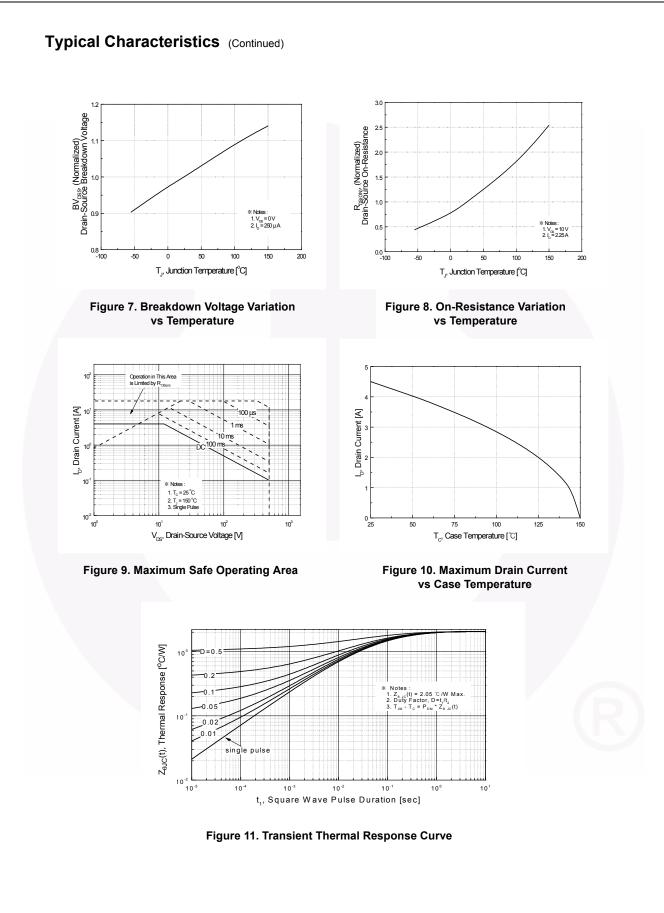
Symbol	Parameter		FQD6N50CTM	Unit
V _{DSS}	Drain-Source Voltage		500	V
I _D	Drain Current - Continuous (T _C = 25°C)		4.5	A
	- Continuous (T _C = 100°C)		2.7	A
I _{DM}	Drain Current - Pulsed	(Note 1)	18	A
V _{GSS}	Gate-Source Voltage		± 30	V
E _{AS}	Single Pulsed Avalanche Energy (Note 2)		300	mJ
I _{AR}	Avalanche Current (Note		4.5	A
E _{AR}	Repetitive Avalanche Energy (Note 1)		6.1	mJ
dv/dt	Peak Diode Recovery dv/dt (Note 3)		4.5	V/ns
	Power Dissipation $(T_A = 25^{\circ}C)^*$		2.5	W
PD	P _D Power Dissipation (T _C = 25°C)		61	W
	- Derate above 25°C		0.49	W/°C
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +150	°C
TL	Maximum lead temperature for soldering purposes, 1/8" from case for 5 seconds		300	°C

Thermal Characteristics

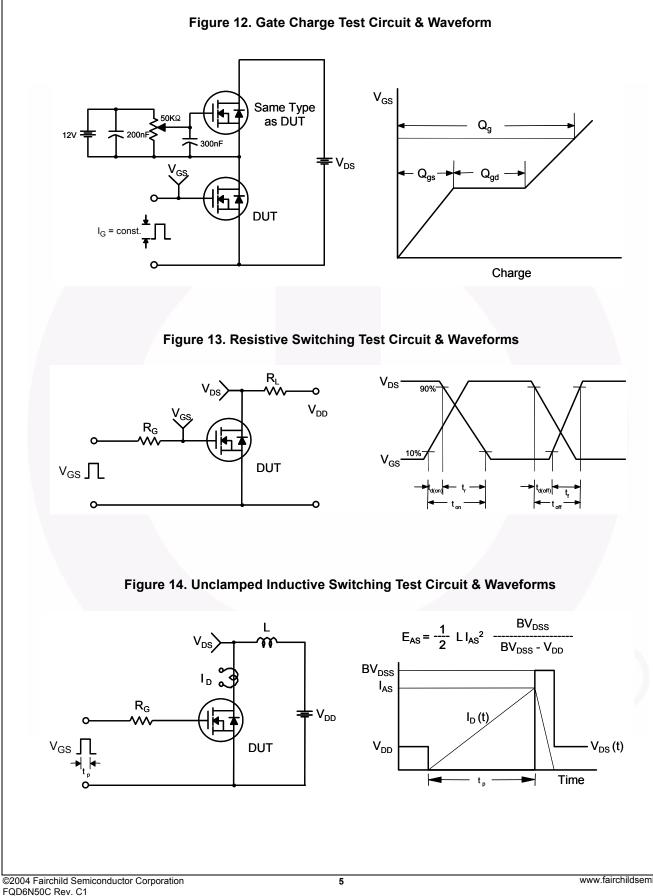
Symbol	Parameter	FQD6N50CTM	Unit
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max.	2.05	
P	Thermal Resistance, Junction-to-Ambient (minimum pad of 2 oz copper), Max.	110	°C/W
$R_{ heta JA}$	Thermal Resistance, Junction-to-Ambient (* 1 in ² pad of 2 oz copper), Max.	50	

FQD			Package	Reel Size	Tupo	Width	acut	antity
Device MarkingDeviceFQD6N50CFQD6N50CTM		D-PAK	330 mm	16 mm		2500 units		
lectric	cal Char	acteristics T _C = 25°C	cunless otherwise	noted.				
Symbol		Parameter	Test Conditions		Min	Тур	Max	Unit
Off Cha	racteristi	cs						
BV _{DSS}		ce Breakdown Voltage	V _{GS} = 0 V, I _D = 250 μA		500			V
ΔBV _{DSS} ΔTJ	5		$I_D = 250 \ \mu\text{A}$, Referenced to 25°C			0.8		V/°C
0			V _{DS} = 500 V, V _{GS} = 0 V				1	μA
DSS	Zero Gate	Zero Gate Voltage Drain Current		$V_{DS} = 400 \text{ V}, T_{C} = 125^{\circ}\text{C}$			10	μA
GSSF	Gate-Body	Leakage Current, Forward	V_{GS} = 30 V, V_{DS}				100	nA
GSSR	-	Leakage Current, Reverse	$V_{GS} = -30 \text{ V}, \text{ V}_{DS}$				-100	nA
On Cha	racteristi	cs						
/ _{GS(th)}		hold Voltage	V _{DS} = V _{GS} , I _D = 250 μA		2.0		4.0	V
R _{DS(on)}	Static Drain On-Resista		$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 2.25 \text{ A}$			1.0	1.2	Ω
FS	Forward Tra	ansconductance	V _{DS} = 40 V, I _D = 2.25A			4.5		S
Dynami	ic Charact	teristics						
C _{iss}	Input Capa	citance	V _{DS} = 25 V, V _{GS} = 0 V, f = 1.0 MHz			540	700	pF
C _{oss}	Output Cap	acitance				80	105	pF
S _{rss}	Reverse Tr	ansfer Capacitance				15	20	pF
Switchi	ng Chara	cteristics						
d(on)	Turn-On De	elay Time	$V_{DD} = 250 \text{ V}, \text{ I}_{D} = 4.5\text{A},$ $R_{G} = 25 \Omega$			10	30	ns
r	Turn-On Ri	se Time				35	80	ns
d(off)	Turn-Off De	elay Time				55	120	ns
f	Turn-Off Fa	III Time		(Note 4)		45	100	ns
ζ ^g	Total Gate	Charge	V _{DS} = 400 V, I _D :	= 4.5A,		19	25	nC
2 _{gs}	Gate-Sourc	e Charge	V _{GS} = 10 V (Note 4)			2.8		nC
2 _{gd}	Gate-Drain	Charge				8.8		nC
Drain-S	ource Dic	ode Characteristics a	nd Maximum F	Ratings				
S		Continuous Drain-Source Dic		-			4.5	Α
SM	Maximum Pulsed Drain-Source Diode F						18	Α
/ _{SD}	Drain-Sour	ce Diode Forward Voltage	$V_{GS} = 0 V, I_{S} = 4.5 A$				1.4	V
rr	Reverse Re	ecovery Time	$V_{GS} = 0 V, I_{S} = 4$	1.5 A,		260		ns
ל ^{ער}	Reverse Re	ecovery Charge	dl _F / dt = 100 A/μs			1.6		μC
TES:	<u>.</u>							
Repetitive R	ating : Pulse widt	h limited by maximum junction temper	rature.					





FQD6N50C — N-Channel QFET[®] MOSFET



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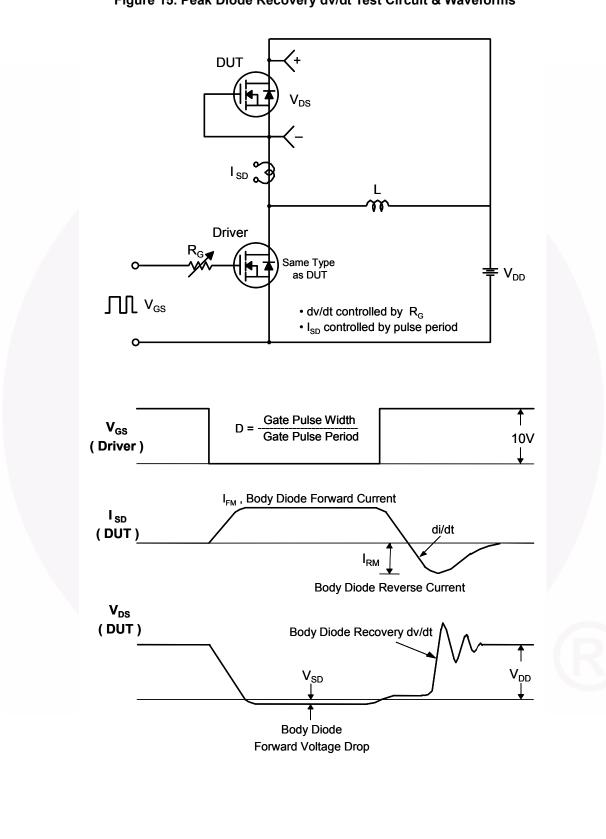
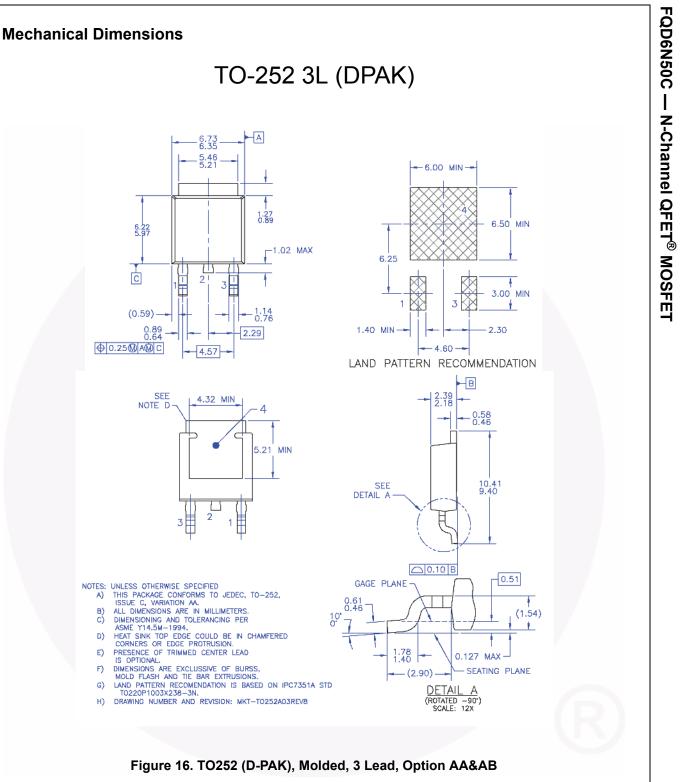


Figure 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms



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Dimension in Millimeters



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